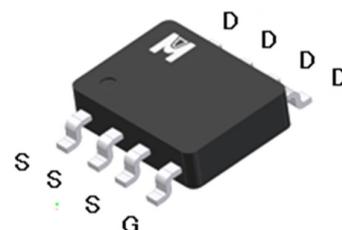
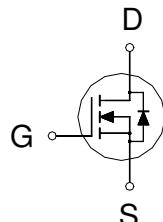




N-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

$BV_{DSS}$	30V
$R_{DS(on)}$ (MAX.)	12mΩ
$I_D$	12A



UIS, Rg 100% Tested

Pb-Free Lead Plating & Halogen Free



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$  Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNIT
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_C = 25^\circ C$	$I_D$	12	A
	$T_C = 100^\circ C$		10	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	48	
Avalanche Current		$I_{AS}$	12	
Avalanche Energy	$L = 0.1mH, I_D=12A, RG=25\Omega$	$E_{AS}$	7.2	mJ
Repetitive Avalanche Energy <sup>2</sup>	$L = 0.05mH$	$E_{AR}$	3.6	
Power Dissipation	$T_A = 25^\circ C$	$P_D$	2.5	W
	$T_A = 100^\circ C$		1	
Operating Junction & Storage Temperature Range		$T_j, T_{stg}$	-55 to 150	°C

100% UIS testing in condition of  $V_D=15V$ ,  $L=0.1mH$ ,  $V_G=10V$ ,  $I_L=15A$ , Rated  $V_{DS}=25V$  N-CH

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Case	$R_{\theta JC}$		25	°C / W
Junction-to-Ambient <sup>3</sup>	$R_{\theta JA}$		50	

<sup>1</sup>Pulse width limited by maximum junction temperature.

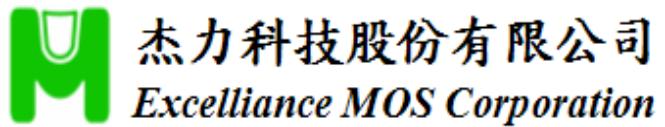
<sup>2</sup>Duty cycle ≤ 1%

<sup>3</sup>50°C / W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	30			V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	1	1.7	3	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24V, V_{GS} = 0V$			1	$\mu\text{A}$
		$V_{DS} = 20V, V_{GS} = 0V, T_J = 125^\circ\text{C}$			25	
On-State Drain Current <sup>1</sup>	$I_{D(\text{ON})}$	$V_{DS} = 5V, V_{GS} = 10V$	12			A
Drain-Source On-State Resistance <sup>1</sup>	$R_{DS(\text{ON})}$	$V_{GS} = 10V, I_D = 12A$		9.5	12	$\text{m}\Omega$
		$V_{GS} = 4.5V, I_D = 10A$		14	17.5	
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = 5V, I_D = 12A$		15		S
DYNAMIC						
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = 15V, f = 1\text{MHz}$		863		$\text{pF}$
Output Capacitance	$C_{oss}$			164		
Reverse Transfer Capacitance	$C_{rss}$			101		
Gate Resistance	$R_g$	$V_{GS} = 15\text{mV}, V_{DS} = 0V, f = 1\text{MHz}$		2.0		$\Omega$
Total Gate Charge <sup>1,2</sup>	$Q_g(V_{GS}=10V)$	$V_{DS} = 15V, V_{GS} = 10V, I_D = 12A$		15		$\text{nC}$
	$Q_g(V_{GS}=4.5V)$			7.4		
Gate-Source Charge <sup>1,2</sup>	$Q_{gs}$			3.1		
Gate-Drain Charge <sup>1,2</sup>	$Q_{gd}$			3.3		
Turn-On Delay Time <sup>1,2</sup>	$t_{d(\text{on})}$	$V_{DS} = 15V, I_D = 1A, V_{GS} = 10V, R_{GS} = 2.7\Omega$		7		$\text{ns}$
Rise Time <sup>1,2</sup>	$t_r$			8		
Turn-Off Delay Time <sup>1,2</sup>	$t_{d(\text{off})}$			10		
Fall Time <sup>1,2</sup>	$t_f$			8		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ )						
Continuous Current	$I_S$	$I_F = I_S, V_{GS} = 0V$			2.5	$\text{A}$
Pulsed Current <sup>3</sup>	$I_{SM}$				10	
Forward Voltage <sup>1</sup>	$V_{SD}$				1.2	V
Reverse Recovery Time	$t_{rr}$	$I_F = I_S, dI_F/dt = 100\text{A}/\mu\text{s}$		18		$\text{ns}$
Peak Reverse Recovery Current	$I_{RM(\text{REC})}$			40		
Reverse Recovery Charge	$Q_{rr}$			10		nC



EMB12N03G

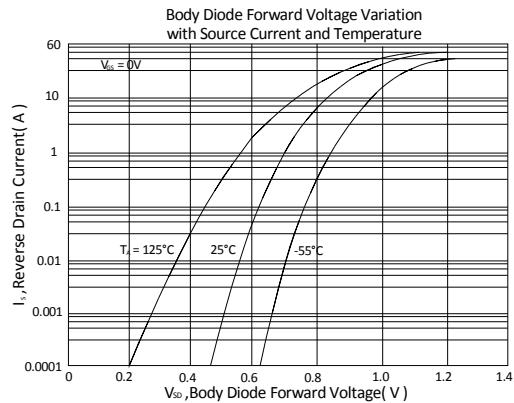
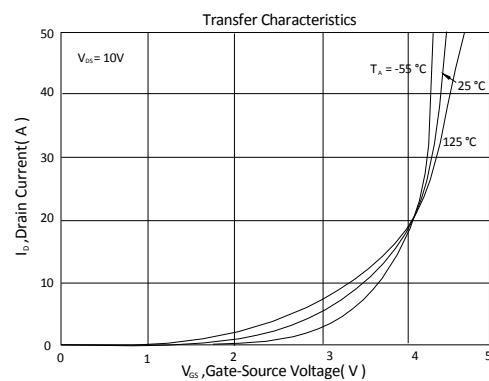
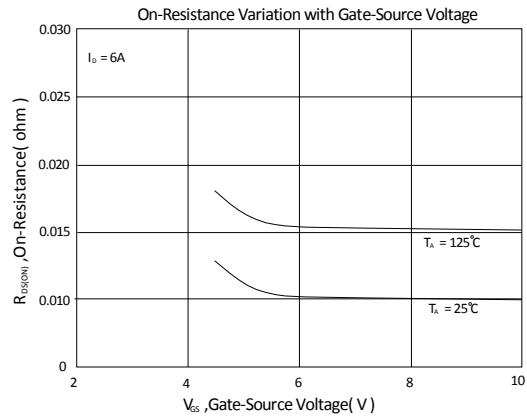
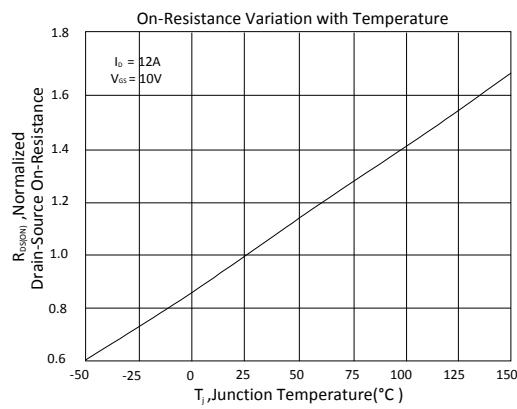
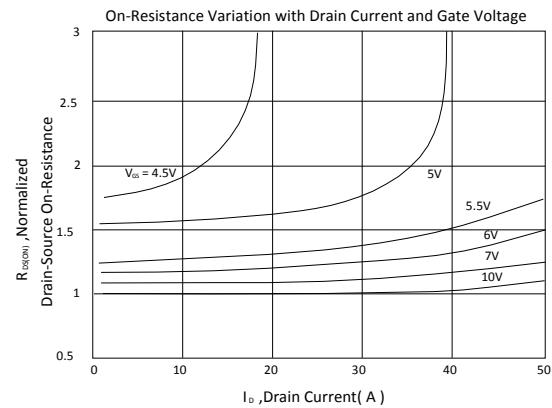
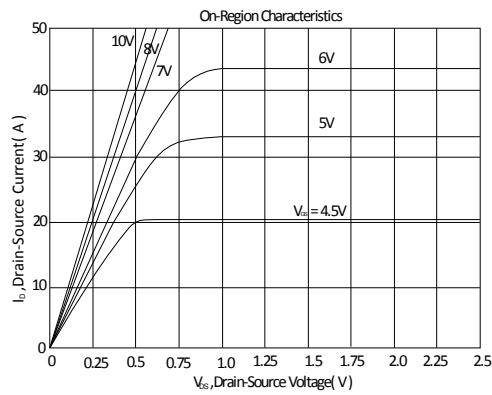
<sup>1</sup>Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.

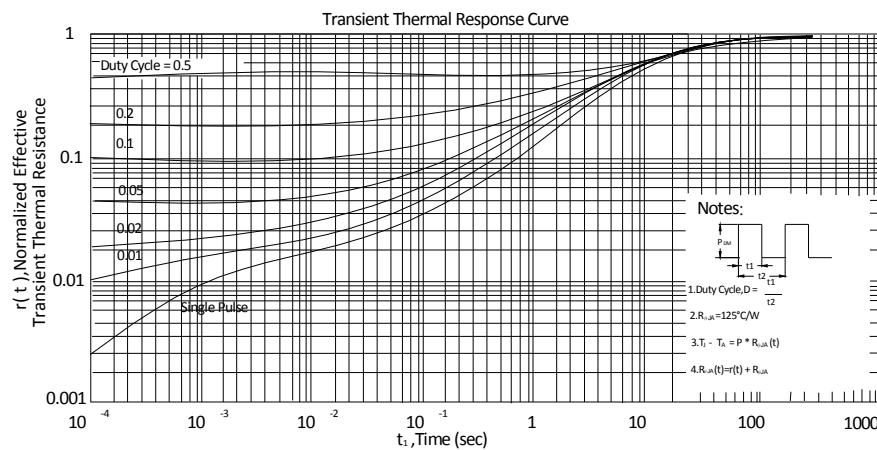
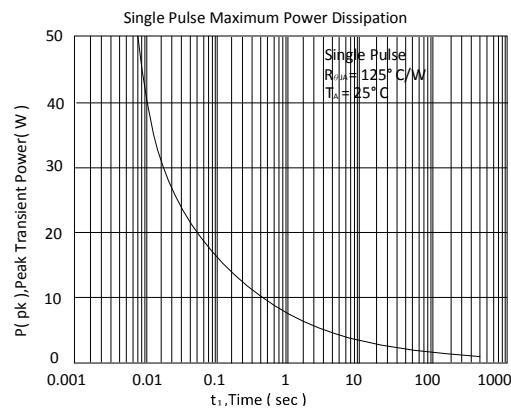
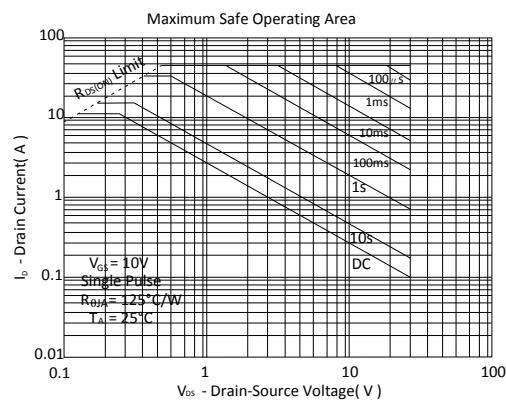
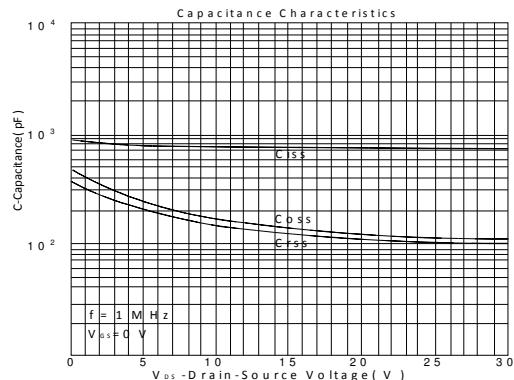
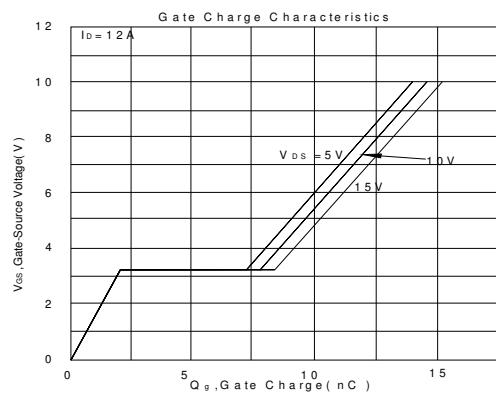
<sup>2</sup>Independent of operating temperature.

<sup>3</sup>Pulse width limited by maximum junction temperature.

EMC will review datasheet by quarter, and update new version.

**TYPICAL CHARACTERISTICS**

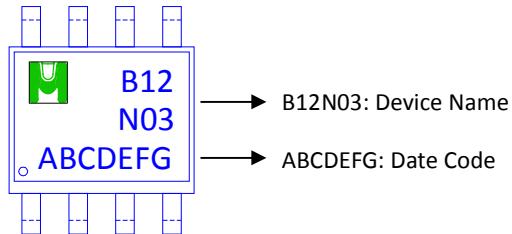




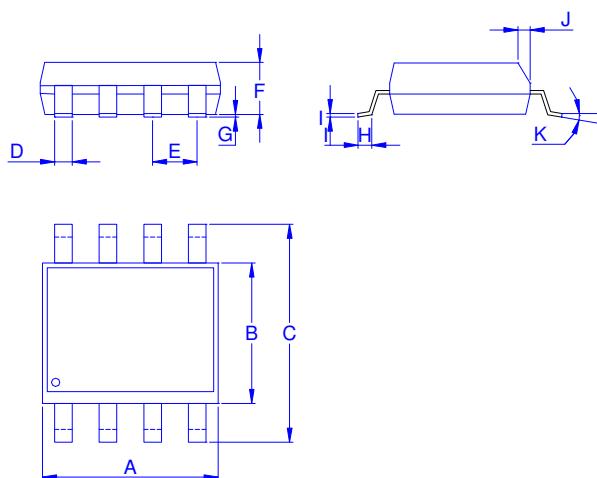


Ordering & Marking Information:

Device Name: EMB12N03G for SOP-8



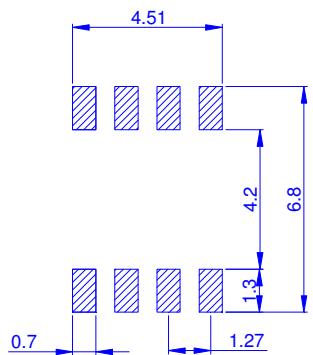
Outline Drawing



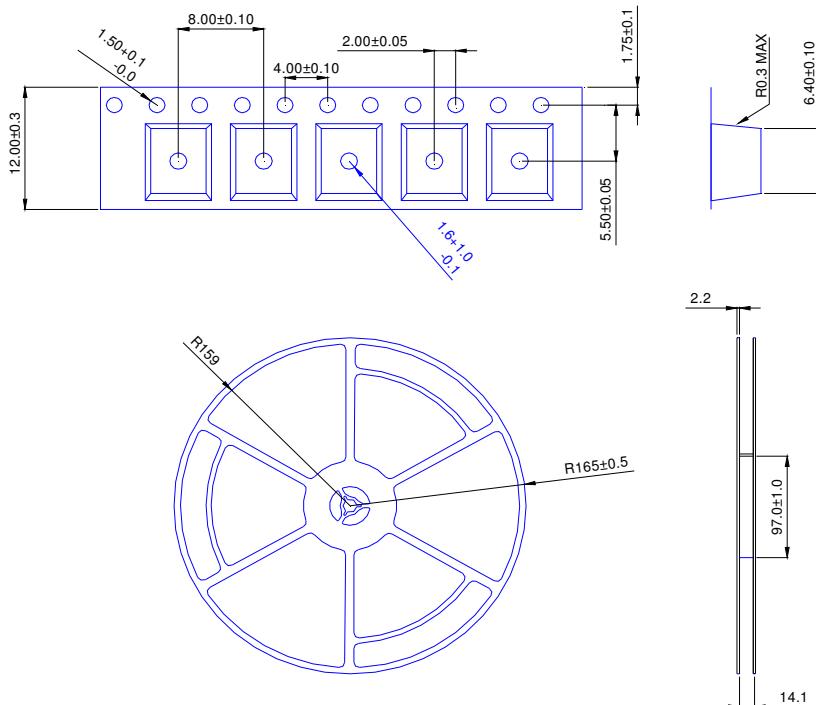
Dimension in mm

Dimension	A	B	C	D	E	F	G	H	I	J	K
Min.	4.70	3.80	5.80	0.31		1.35	0.01	0.40	0.10	0.25	0°
Typ.	4.90	3.90	6.00	0.41	1.27	1.55	0.18	0.60	0.20	0.30	
Max.	5.10	4.00	6.20	0.51		1.75	0.25	1.27	0.25	0.50	8°

Footprint



Tape&Reel Information:2500pcs/Reel



產品別	SOP-8
Reel 尺寸	13"
編帶方式	FEED DIRECTION  
前空格	25
後空格	50
裝箱數	
滿捲數量	2.5K
捲/內盒比	1 : 1
內盒滿箱數	2.5K
內/外箱比	10 : 1
外箱滿箱數	25K